# Surface Mount - DFN10\*8\*3 - 3 kA





#### **Maximum Ratings and Thermal Characteristics**

(T<sub>A</sub> = 25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit
Operating Junction Temperature	T	-55 to 125	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C
Current Rating <sup>1</sup>	I <sub>PP</sub>	3	kA
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	70	°C/W
Thermal Resistance Junction to Case	R <sub>eJC</sub>	20	°C/W

#### Note:

1. Rated I<sub>pp</sub> measured with 8/20 µS pulse.

### **Agency Approvals**

Agency	Agency File Number
<b>71</b> °	E230531

### **Functional Diagram**



# **Description**

The DFNAK3 series offers a clamping voltage lower than alternative technologies such as MOVs and GDTs. Rated to 3 kA (8/20  $\mu s$ ) surge current, DFNAK3 series offers a high level of protection for mission critical and high reliability applications. It aids compliance to surge requirements such as IEC 61000-4-5 (Level 4). The compact surface mount DFN10\*8\*3 package is compatible with automated PCBA processes and enables high power density designs.

### **Features**

- Compact surface mount DFN10\*8\*3package
- Ideal for automated PCBA processes with reduced manufacturing cost and increased soldering quality as compared to axial leaded packages
- Foldback technology for superior clamping factor
- V<sub>BR</sub> @ T<sub>J</sub> = V<sub>BR</sub> @25 °C x (1+αT x (T<sub>J</sub> 25))(αT:Temperature Coefficient, typical value is 0.1 %)
- Glass passivated chip junction
- ESD protection of data lines in accordance with IEC 61000-4-2, 30 kV(Air), 30 kV (Contact)

- Low dynamic resistance enabling superior low clamping voltage
- UL recognized compound meeting flammability rating UL94 V-0
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- Halogen free and RoHS compliant
- Pb-free E3 means 2<sup>nd</sup> level interconnect is Pb-free and the terminal finish material is tin (Sn) (IPC/JEDEC J-STD-609A.01)

# **Applications**

DFNAK3 series is ideal for the protection of I/O Interfaces,  $V_{\text{cc}}$  bus and other vulnerable circuits used in ICT, Industrial and Consumer electronic applications.

It aids compliance to surge requirements such as IEC 61000-4-5 (Level 4) for interfaces used in exposed PoE ports, Small Cells, Remote Radio Units (RRUs) and Baseband Units (BBUs), and other high power DC bus in harsh environments.



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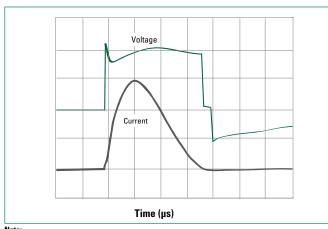
## **Electrical Characteristics** (T<sub>A</sub> = 25 °C unless otherwise noted)

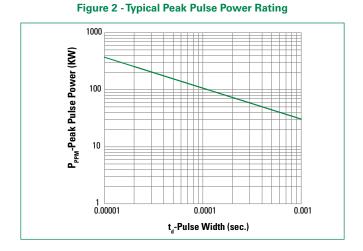
Part Numbers (Bi)	Marking	Standoff Voltage (V <sub>R</sub> ) (V)	Max Reverse Leakage (I <sub>R</sub> ) @V <sub>R</sub>		Breakdown (V <sub>BR</sub> ) @ I <sub>T</sub>	Test Current I <sub>T</sub>	V <sub>c</sub> @ Pea	mping Voltage k Pulse Current (8/20 µs)	Max. Capacitance 0 Bias 10 kHz	Agency Approval
(51)		(0,	(μΑ)	Min (V)	Max (V)	(mA)	V <sub>CL</sub> (V)	I <sub>PP</sub> (A)	(nF)	74
DFNAK3-058C-D1	58C3K	58	10	64	70	10	100	3000	3.1	Χ
DFNAK3-066C-D1	66C3K	66	10	72	80	10	110	3000	2.7	Χ
DFNAK3-072C-D1	72C3K	72	10	80	90	10	120	3000	2.4	Χ
DFNAK3-076C-D1	76C3K	76	10	85	95	10	125	3000	2.2	Χ
DFNAK3-080C-D1	80C3K	80	10	89	100	10	130	3000	2.1	Χ

Note: Using 8/20  $\mu\text{S}$  wave shaped defined in IEC 61000-4-5.

## Ratings and Characteristic Curves ( $T_A = 25$ °C unless otherwise noted)

Figure 1 - Surge Response (8/20 Surge current waveform)





The power dissipation causes a change in avalanche voltage during the surge and the avalanche voltage eventually returns to the original value when the transient has passed.



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Figure 3 - Pulse Waveform

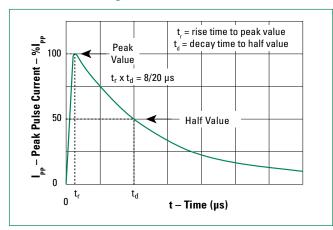
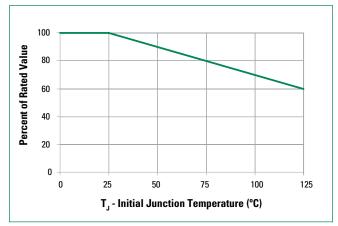


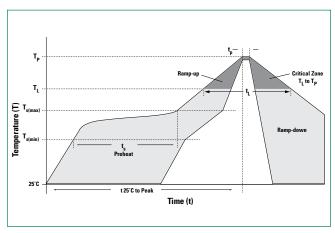
Figure 4 - Peak Power Derating



Please contact Littelfuse for reliability or FIT/MTBF data, the performance is subject to vary and depends on the end customers' application condition.

#### **Soldering Parameters**

Reflow Con	Lead-free assembly		
	-Temperature Min (T <sub>s(min)</sub> )	150 °C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200 °C	
	-Time (min to max) (t <sub>s</sub> )	60 – 120 seconds	
Average Ra	3 °C/second max		
T <sub>S(max)</sub> to T <sub>A</sub>	3 °C/second max		
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217 °C	
nellow	-Time (min to max) (T <sub>s</sub> )	60 – 150 seconds	
Peak Tempe	Peak Temperature (T <sub>P</sub> )		
Time within	30 seconds		
Ramp-down	6 °C/second max		
Time 25 °C	8 minutes max		
Do Not Exc	250 °C		



### **Physical Specifications**

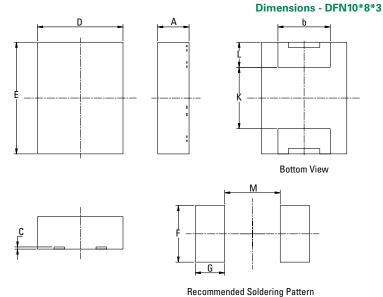
Weight	0.0282 ounce, 0.7998 grams
Case	UL recognized compound meeting flammability rating UL94 V-0
Terminal	Matte tin-plated leads, solderable per JESD22-B102

#### **Environmental Specifications**

High Temp Voltage Blocking (HTRB)	100 % DC reverse voltage rated 125 °C, 1008 hours JEDEC, JESD22-A-108
Biased Temp & Humidity (H3TRB)	80 % breakdown voltage (+85 °C) 85 %RH, 1008 hours JEDEC, JESD22-A-101
Unbiased Highly Accelerated Stress Test (UHAST)	96 hours at $T_A = 130$ °C/85 %RH. JEDEC, JESD22-A-118
Temp Cycling (TC)	-55 °C to +125 °C, 15 min. dwell, 1000 cycles. JEDEC, JESD22-A104
Moisture Sensitivity Level (MSL)	85 %RH, +85 °C, 168 hours, 3 reflow cycles (+250 °C Peak). JEDEC, JEDEC-J-STD-020. Level 1
Resistance to Solder Heat (RSH)	+260 °C, 30 seconds JEDEC, JEDEC JESD22-A-111



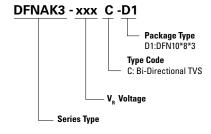
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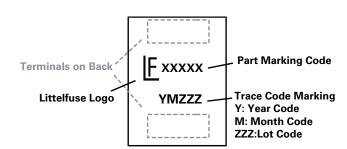
Dii	Millin	neters	Inches		
Dimensions	Min	Max	Min	Max	
Α	2.90	3.10	0.114	0.122	
b	4.80	5.20	0.189	0.205	
С	0.22	0.28	0.009	0.011	
D	8.00	8.20	0.315	0.323	
E	10.50	10.70	0.413	0.421	
F	5.40	REF	0.213 REF		
G	2.80	REF	0.110 REF		
K	5.85	TYP	0.230 TYP		
L	2.20	2.60	0.087	0.102	
M	5.30	REF	0.209 REF		

Dimensions are only for reference and might be changed later on. But the soldering pattern is fixed.

# **Part Numbering System**



## **Part Marking System**

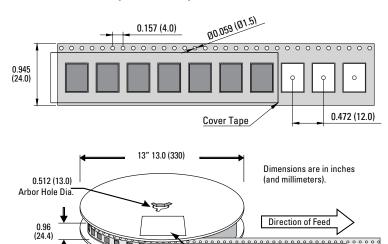




## **Packing Option**

Part Number	Component Package	Quantity	Packaging Option	Packaging Specification
DFNAK3-xxxX-D1	DFN10*8*3	1500	Tape & Reel -24 mm tape/13" reel	EIA STD RS-481

### **Tape and Reel Specification**



Label

